


300V PNP HIGH VOLTAGE TRANSISTOR IN SOT23

Features

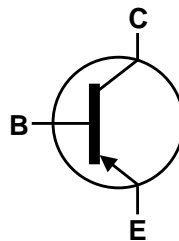
- $BV_{CEO} > -300V$
- $I_C = -0.2A$ Continuous Collector Current
- $I_{CM} = -1A$ Peak Pulse Current
- Complementary NPN Type: FMMT497
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

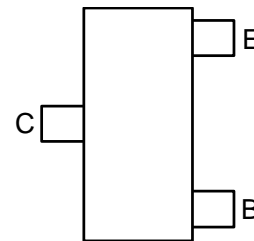
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads; Solderable per
MIL-STD-202, Method 208 
- Weight 0.008 grams (Approximate)



Top View



Device Symbol



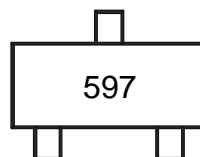
Top View
Pin-Out

Ordering Information (Note 4)

| Part Number | Compliance | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|-------------|------------|---------|--------------------|-----------------|-------------------|
| FMMT597TA | AEC-Q101 | 597 | 7 | 8 | 3,000 |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



597 = Product Type Marking Code

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | -300 | V |
| Collector-Emitter Voltage | V _{CEO} | -300 | V |
| Emitter-Base Voltage | V _{EBO} | -7 | V |
| Continuous Collector Current | I _C | -0.2 | A |
| Peak Pulse Current | I _{CM} | -1 | A |
| Base Current | I _B | -200 | mA |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

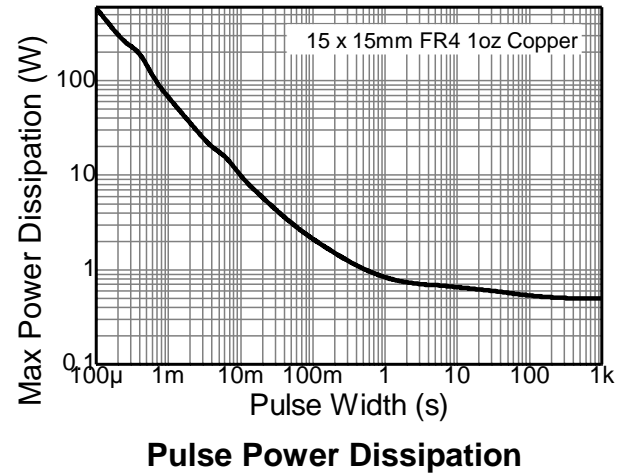
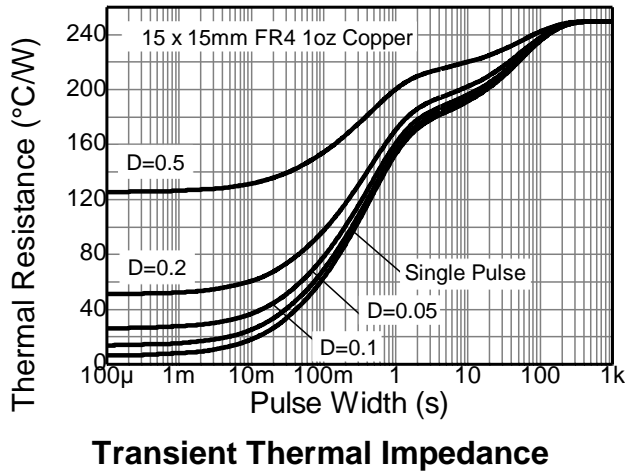
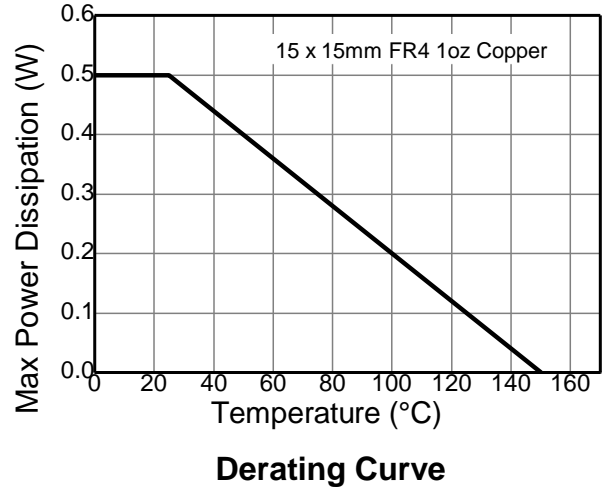
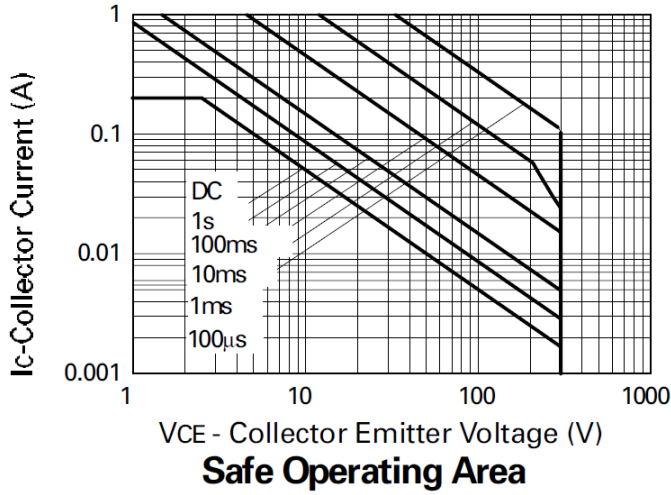
| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 5) | P _D | 500 | mW |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{θJA} | 250 | °C/W |
| Thermal Resistance, Junction to Lead (Note 6) | R _{θJL} | 197 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

ESD Ratings (Note 7)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | C |

- Notes:
- For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 - Thermal resistance from junction to solder-point (at the end of the collector lead).
 - Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics and Derating Information

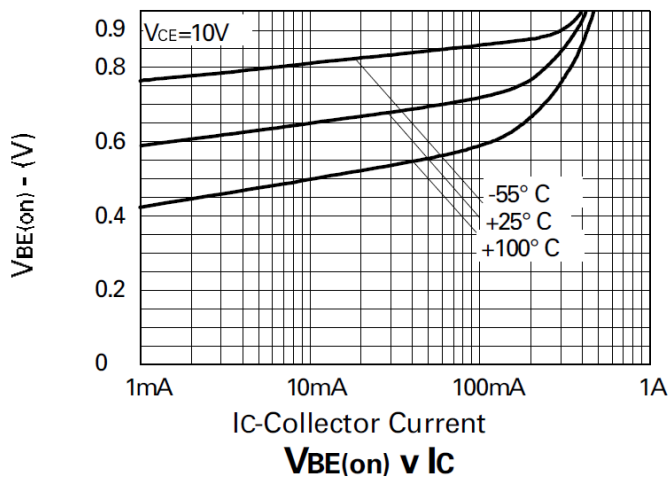
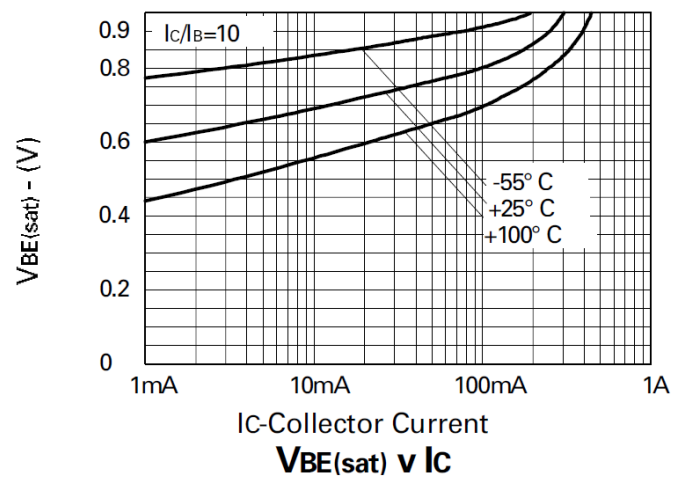
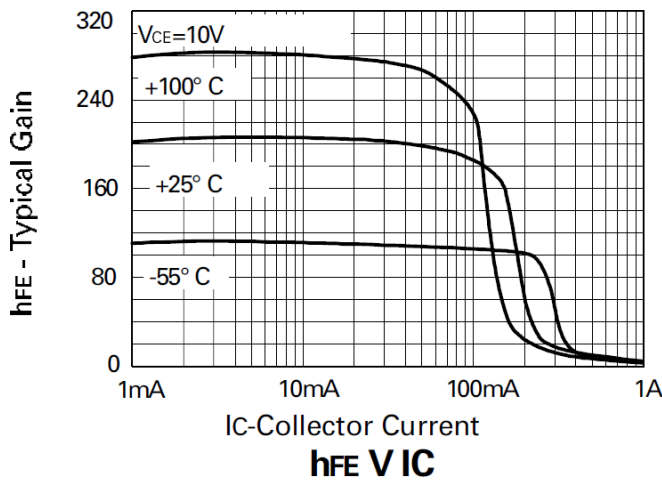
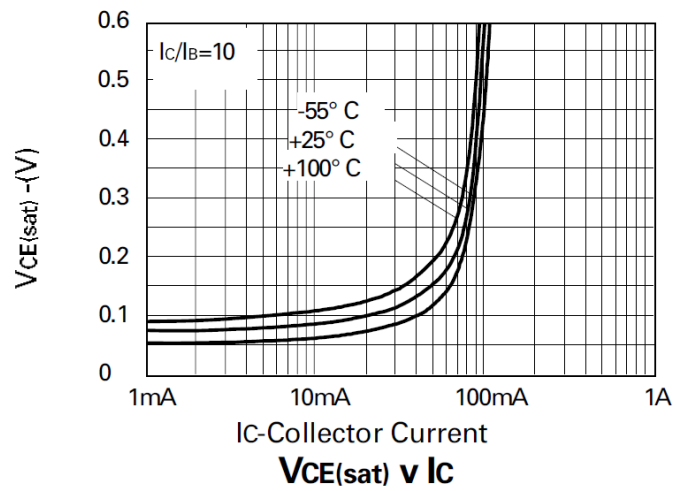
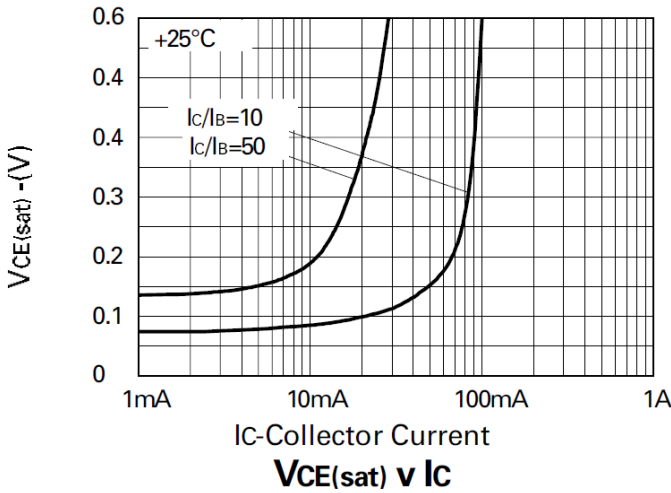


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--|----------------------|------|------|--------------|------|--|
| Collector-Base Breakdown Voltage | BV _{CBO} | -300 | — | — | V | I _C = -100μA |
| Collector-Emitter Breakdown Voltage (Note 8) | BV _{CEO} | -300 | — | — | V | I _C = -10mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -7 | -8.1 | — | V | I _E = -100μA |
| Collector-Base Cut-Off Current | I _{CBO} | — | <1 | -100 | nA | V _{CB} = -250V |
| Emitter-Base Cut-Off Current | I _{EBO} | — | <1 | -100 | nA | V _{EB} = -4V |
| Collector-Emitter Cut-Off Current | I _{CES} | — | <1 | -100 | nA | V _{CE} = -250V |
| Static Forward Current Transfer Ratio (Note 8) | h _{FE} | 100 | — | — | — | I _C = -1mA, V _{CE} = -10V |
| | | 100 | — | 300 | | I _C = -50mA, V _{CE} = -10V |
| | | 100 | — | — | | I _C = -100mA, V _{CE} = -10V |
| Collector-Emitter Saturation Voltage (Note 8) | V _{CE(SAT)} | — | — | -250 -250 | mV | I _C = -50mA, I _B = -5mA I _C = -100mA, I _B = -20mA |
| Base-Emitter Saturation Voltage (Note 8) | V _{BE(SAT)} | — | — | -1000 | mV | I _C = -100mA, I _B = -20mA |
| Base-Emitter Turn-On Voltage (Note 8) | V _{BE(ON)} | — | — | -850 | mV | I _C = -100mA, V _{CE} = -10V |
| Transition Frequency | f _T | 75 | — | — | MHz | V _{CE} = -10V, I _C = -50mA, f = 100MHz |
| Output Capacitance | C _{obo} | — | — | 10 | pF | V _{CB} = -10V, f = 1MHz |

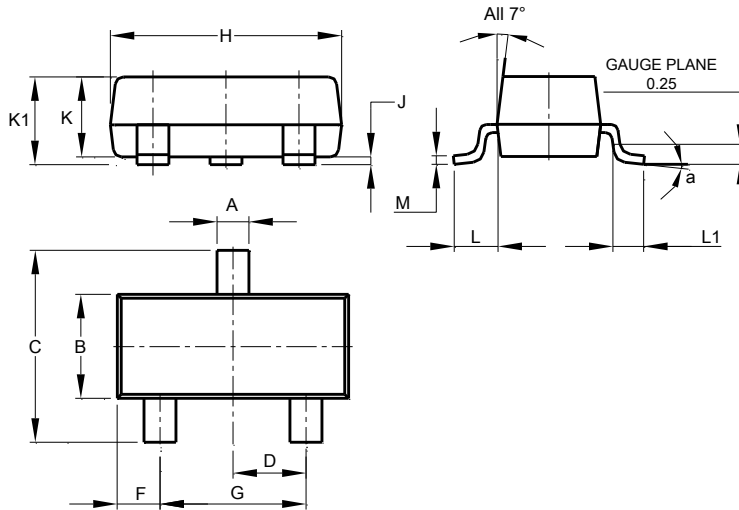
Note: 8. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



Package Outline Dimensions

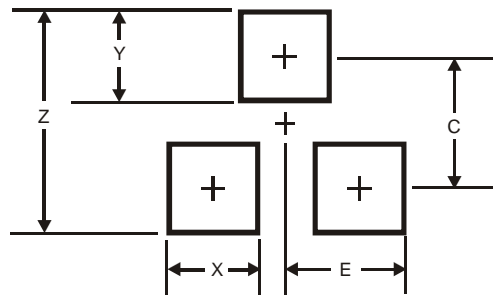
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



| SOT23 | | | |
|----------------------|-------|-------|-------|
| Dim | Min | Max | Typ |
| A | 0.37 | 0.51 | 0.40 |
| B | 1.20 | 1.40 | 1.30 |
| C | 2.30 | 2.50 | 2.40 |
| D | 0.89 | 1.03 | 0.915 |
| F | 0.45 | 0.60 | 0.535 |
| G | 1.78 | 2.05 | 1.83 |
| H | 2.80 | 3.00 | 2.90 |
| J | 0.013 | 0.10 | 0.05 |
| K | 0.890 | 1.00 | 0.975 |
| K1 | 0.903 | 1.10 | 1.025 |
| L | 0.45 | 0.61 | 0.55 |
| L1 | 0.25 | 0.55 | 0.40 |
| M | 0.085 | 0.150 | 0.110 |
| a | 8° | | |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| Z | 2.9 |
| X | 0.8 |
| Y | 0.9 |
| C | 2.0 |
| E | 1.35 |

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device terminals and PCB tracking.

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